Supporting Information

Ligand strategy retarding monovalent copper oxidation toward achieving Cs₃Cu₂I₅ perovskite emitter with enhanced stability for lightings

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Figure S1 The SEM images of (a) pure and (b) EDTA-Cs₃Cu₂I₅. Particle size distribution histograms (c) pure and (d) EDTA-Cs₃Cu₂I₅.



Figure S2 The crystal structure of $Cs_3Cu_2I_5$.



Figure S3 (a-f) EDS elemental mapping images of Cs, Cu, I, C and N of $Cs_3Cu_2I_5$ powder.



Figure S4 (a) The N/Cu ratio of $Cs_3Cu_2I_5$ and EDTA- $Cs_3Cu_2I_5$ samples. (b) The atomic ratio of EDTA- $Cs_3Cu_2I_5$ tested by EDS semiquantitative analysis.



Figure S5 (a) The structural of EDTA. (b) X-ray photoelectron spectra (XPS) of $Cs_3Cu_2I_5$ and EDTA- $Cs_3Cu_2I_5$. (c)The N ration of $Cs_3Cu_2I_5$ and EDTA- $Cs_3Cu_2I_5$. (d) XPS spectra of Cs 3d.



Figure S6 XPS Cu 2p spectra of pure and EDTA-treated samples.



Figure S7 The PL spectra of (a) $Cs_3Cu_2I_5$ and (b) EDTA- $Cs_3Cu_2I_5$ at different storage periods in air ambient.



Figure S8 The PL spectra of EDTA-Cs₃Cu₂I₅-LED device under different driving voltage.

| Sample | \mathbf{A}_{1} | τ_1 (ns) | A_2 | $	au_2$ (ns) | $	au_{avg}$ (ns) |
|---|------------------|---------------|-------|--------------|------------------|
| $Cs_3Cu_2I_5$ | 511 | 637 | 2586 | 1289 | 1230 |
| EDTA-Cs ₃ Cu ₂ I ₅ | 457 | 406 | 2528 | 1089 | 1045 |

Table S1 Time-resolved PL decay curves of the pure and EDTA-treated $Cs_3Cu_2I_5$ samples.